



# MBRD650CT MBRD660CT

SCHOTTKY RECTIFIER

6 Amp



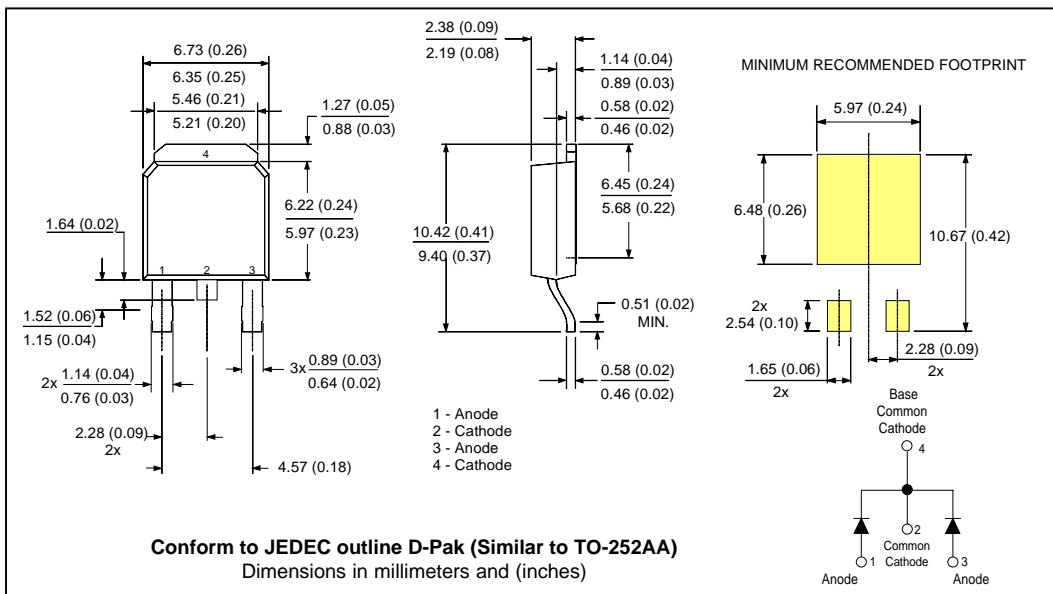
### Major Ratings and Characteristics

| Characteristics                              | MBRD650CT<br>MBRD660CT | Units      |
|--|------------------------|------------|
| $I_{F(AV)}$ Rectangular waveform             | 6                      | A          |
| $V_{RRM}$                                    | 50 - 60                | V          |
| $I_{FSM}$ @ $t_p = 5 \mu s$ sine             | 490                    | A          |
| $V_F$ @ 3 Apk, $T_J = 125^\circ C$ (per leg) | 0.65                   | V          |
| $T_J$ range                                  | -40 to 150             | $^\circ C$ |

### Description/ Features

The MBRD650CT, MBRD660CT surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

| Part number  | MBRD650CT | MBRD660CT |
|--|-----------|-----------|
| V <sub>R</sub> Max. DC Reverse Voltage (V)             | 50        | 60        |
| V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V) |           |           |

Absolute Maximum Ratings

| Parameters  | Value     | Units | Conditions  |
|---|-----------|-------|---|
| I <sub>F(AV)</sub> Max. Average Forward (Per Leg) Current * See Fig. 5 (Per Device) | 3.0<br>6  | A     | 50% duty cycle @ T <sub>C</sub> = 128°C, rectangular wave form  |
| I <sub>FSM</sub> Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7      | 490<br>75 | A     | 5µs Sine or 3µs Rect. pulse<br>10ms Sine or 6ms Rect. pulse<br>Following any rated load condition and with rated V <sub>RRM</sub> applied |
| E <sub>AS</sub> Non-Repet. Aval. Energy (Per Leg)                                   | 6         | mJ    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 Amp, L = 12 mH  |
| I <sub>AR</sub> Repetitive Avalanche Current (Per Leg)                              | 0.6       | A     | Current decaying linearly to zero in 1 µsec<br>Frequency limited by T <sub>J</sub> max. V <sub>A</sub> = 1.5 x V <sub>R</sub> typical     |

Electrical Specifications

| Parameters  | Value | Units | Conditions  |
|---|-------|-------|---|
| V <sub>FM</sub> Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)    | 0.7   | V     | @ 3A  |
|   | 0.9   | V     | @ 6A  |
|   | 0.65  | V     | @ 3A  |
|   | 0.85  | V     | @ 6A  |
| I <sub>RM</sub> Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1) | 0.1   | mA    | T <sub>J</sub> = 25 °C  |
|   | 15    | mA    | T <sub>J</sub> = 125 °C   |
| C <sub>T</sub> Typ. Junction Capacitance (Per Leg)                      | 145   | pF    | V <sub>R</sub> = 5V <sub>DC</sub> (test signal range 100Khz to 1Mhz) 25°C |
| L <sub>S</sub> Typical Series Inductance (Per Leg)                      | 5.0   | nH    | Measured lead to lead 5mm from package body                               |
| dv/dt Max. Voltage Rate of Change                                       | 10000 | V/µs  | (Rated V <sub>R</sub> )   |

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

| Parameters  | Value      | Units   | Conditions                |
|---|------------|---------|---------------------------|
| T <sub>J</sub> Max. Junction Temperature Range (*)                                | -40 to 150 | °C      |                           |
| T <sub>stg</sub> Max. Storage Temperature Range                                   | -40 to 150 | °C      |                           |
| R <sub>thJC</sub> Max. Thermal Resistance (Per Leg) Junction to Case (Per Device) | 6          | °C/W    | DC operation * See Fig. 4 |
|   | 3          |         |                           |
| R <sub>thJA</sub> Max. Thermal Resistance Junction to Ambient                     | 80         | °C/W    |                           |
| wt Approximate Weight   | 0.3 (0.01) | g (oz.) |                           |
| Case Style  | D-Pak      |         | Similar to TO-252AA       |

(\*)  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

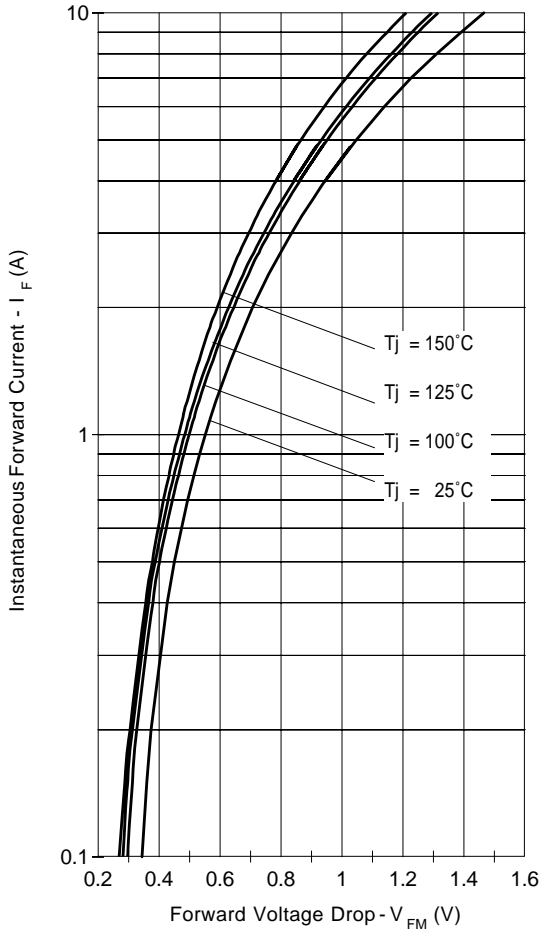


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

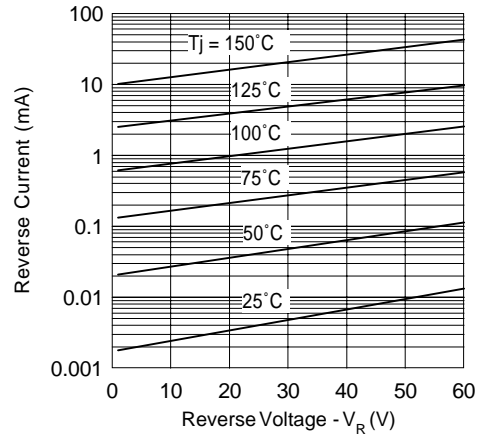


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

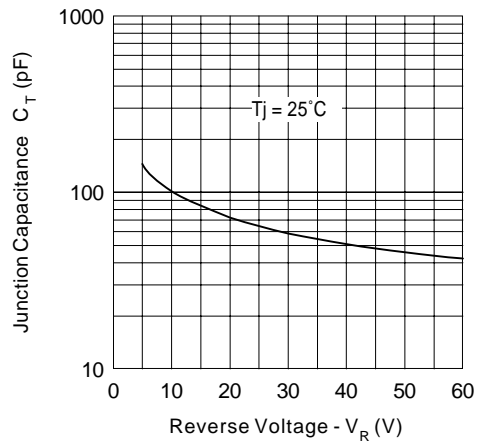


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

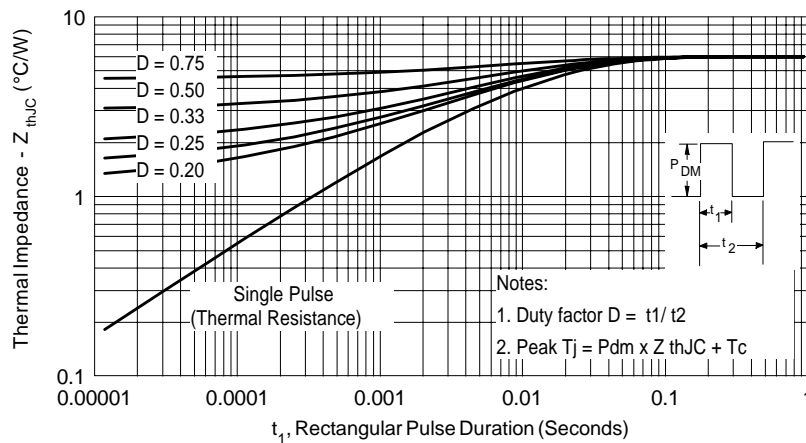


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

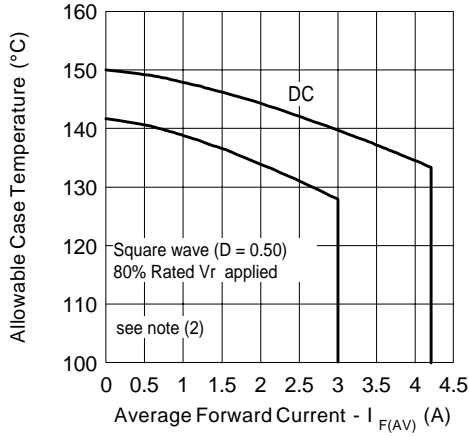


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

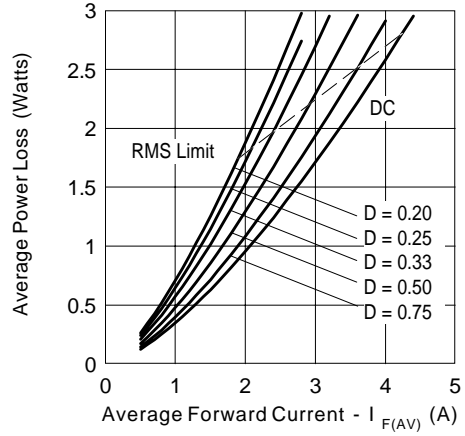


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

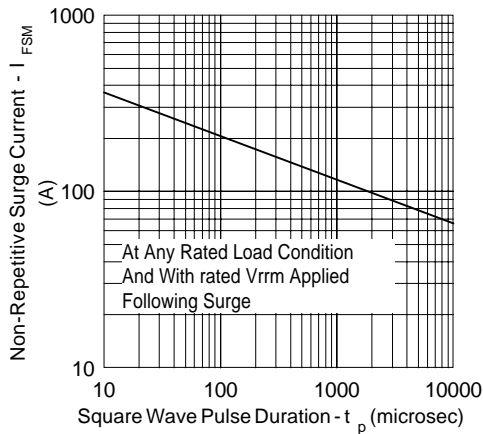
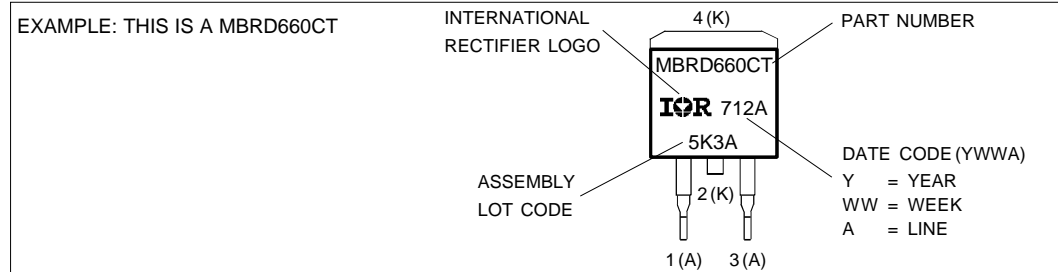


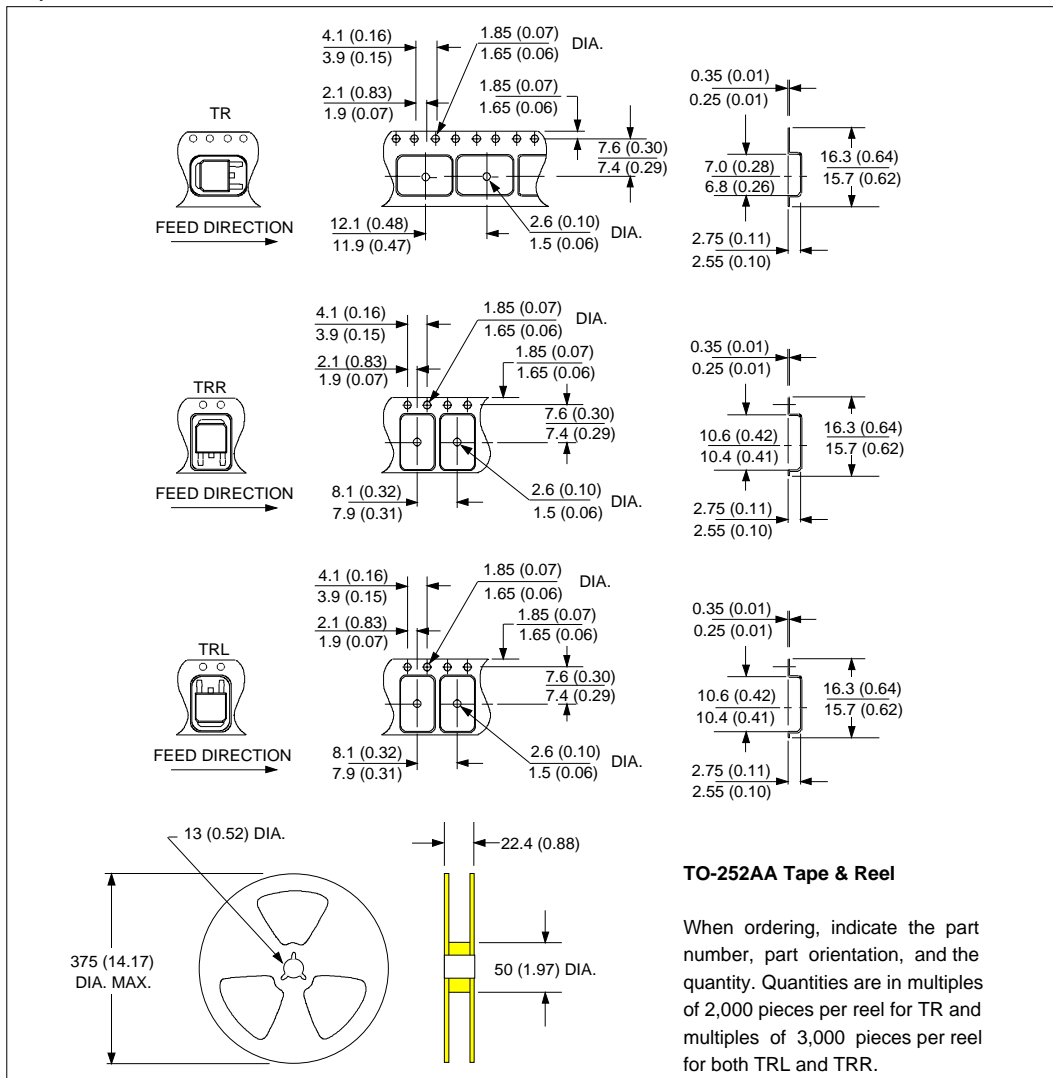
Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

- (2) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;  
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$  (see Fig. 6);  
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Marking Information



Tape & Reel Information



MBRD650CT, MBRD660CT

Bulletin PD-20755 rev. C 03/03

International  
**IOR** Rectifier

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

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